2SC4672

NPN SILICON TRANSISTOR

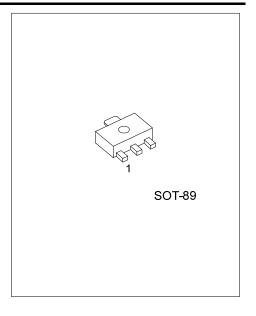
LOW FREQUENCY TRANSISTOR (50V,2A)

■ DESCRIPTION

The UTC **2SC4672** is a low frequency transistor. Excellent DC current gain characteristics.

■ FEATURES

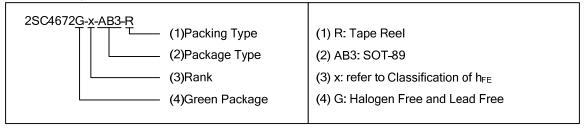
*Low Saturation Voltage, Typically $V_{CE(SAT)}$ =0.1V at I_C / I_B =1A / 50mA *Excellent DC Current Gain Characteristics



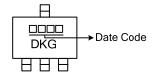
ORDERING INFORMATION

Ouden Ni web en	Package	Pin Assignment			Daakina	
Order Number		1	2	3	Packing	
2SC4672G-x-AB3-R	SOT-89	В	С	Е	Tape Reel	

Note: Pin Assignment: B: Base C: Collector E: Emitter



■ MARKING



<u>www.unisonic.com.tw</u> 1 of 2

■ ABSOLUATE MAXIUM RATINGS (T_A= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V _{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	6	V
Collector Current	lc	2	Α
Collector Current (Pulse) (Note 1)	I _{CP}	5	Α
Collector Dissipation	Pc	500	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

Note: 1.Single pulse, Pw=10ms

■ **ELECTRICAL CHARACTERISTICS** (T_A= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =50μA	60			V
Collector-Emitter Breakdown Voltage	BV_CEO	I _C =1mA	50			V
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =50μA	6			V
Collector Cutoff Current	I _{CBO}	V _{CB} =60V			0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V			0.1	μΑ
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I _C /I _B =1A/50mA (Note)		0.1	0.35	V
DC Current Transfer Ratio	h _{FE}	V _{CE} =2V, I _C =0.5A (Note)	120		400	
Transition Frequency	f⊤	V _{CE} =2V, I _E =-0.5A, f=100MHz		210		MHz
Output Capacitance	Сов	V _{CB} =10V, I _E =0A,f=1MHz		25		pF

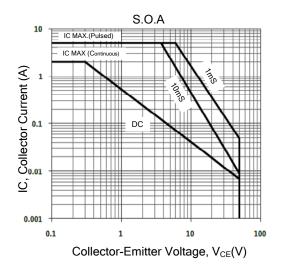
Note: Measured using pulse current.

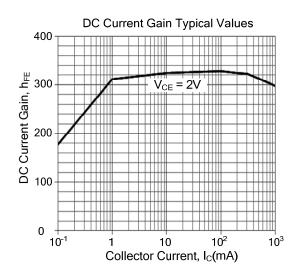
■ CLASSIFICATION OF h_{FE}

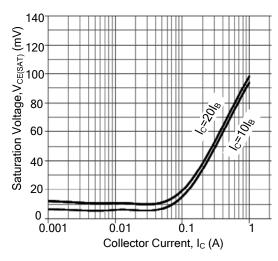
RANK	Α	В
RANGE	120 ~ 240	200 ~ 400

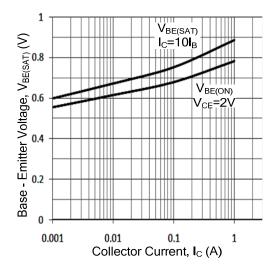
^{2.} Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

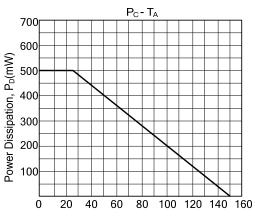
■ TYPICAL CHARACTERISTICS











Ambient Temperature, T_a(°C)

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Unisonic manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H MMBT-2369-TR BC546/116 BC557/116 BSW67A NJVMJD148T4G NTE123AP-10 NTE153MCP NTE16

NTE195A NTE92 C4460 2N4401-A 2N6728 2SA1419T-TD-H 2SA2126-E 2SB1204S-TL-E 2SC2712S-GR,LF 2SC5488A-TL-H

2SD2150T100R SP000011176 2N2907A 2N3904-NS 2N5769 2SC2412KT146S 2SD1816S-TL-E CPH6501-TL-E MCH4021-TL-E

MJE340 US6T6TR NJL0281DG 732314D CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E

NJL0302DG 2N3583 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE26 NTE282 NTE323 NTE350 NTE81 STX83003-AP